<ul> <li>Low Output Skew, Low Pulse Skew for Clock-Distribution and Clock-Generation</li> </ul>	DW PACKAGE (TOP VIEW)
Applications	
TTL-Compatible Inputs and Outputs	1Y1 2 23 1Y3
<ul> <li>Two Banks Distribute One Clock Input to Three Same Frequency Clock Outputs</li> </ul>	1Y2 🛛 3 22 🗍 1A
Three Same-Frequency Clock Outputs	GND 4 21 V <sub>CC</sub>
<ul> <li>One Bank Distributes One Clock Input to Four Half-Frequency Clock Outputs</li> </ul>	2Q1 [] 5 20 ] PRE 2OE [] 6 19 [] 2Q3
<ul> <li>Internal Power-Up Circuit</li> </ul>	2OE 6 19 2Q3 2A 7 18 GND
<ul> <li>Distributed V<sub>CC</sub> and Ground Pins Reduce</li> </ul>	2Q2 8 17 2Q4
Switching Noise	GND 🛛 9 16 🗍 V <sub>CC</sub>
<ul> <li>Symmetrical Output Drive (–32-mA I<sub>OH</sub>,</li> </ul>	3Y1 0 15 3OE
32-mA I <sub>OL</sub> )	3Y2 11 14 3Y3
<ul> <li>State-of-the-Art EPIC-IIB™ BiCMOS Design</li> </ul>	GND 12 13 3A
Significantly Reduces Power Dissipation	

• Packaged in Plastic Small-Outline Package

#### description

The CDC330 is a high-performance, low-skew clock driver. It is specifically designed for applications requiring output signals at both the primary clock frequency and one-half the primary clock frequency.

This device contains two banks that fan out one input to three same-frequency outputs and one bank that fans out one input to four half-frequency outputs with minimum skew for clock distribution. Each bank of Y outputs switch in phase and at the same frequency as its clock (A) input. The four Q outputs switch at one-half the frequency of their clock  $(2\overline{A})$  input.

When the output-enable ( $2\overline{OE}$ ) input is low and the preset ( $\overline{PRE}$ ) input is high, the Q outputs toggle on high-to-low transitions of  $2\overline{A}$ . Taking  $\overline{PRE}$  low asynchronously presets the Q outputs to the high level. When a bank's  $\overline{OE}$  input is high, the outputs are in the high-impedance state.

The CDC330 is characterized for operation from 0°C to 70°C.

INPU	JTS	OUTPUTS	
nOE	nA	nY1–nY3	
Н	Х	Z	
L	L	L	
L	н	н	

FUNCTION	TADLEC
FUNCTION	IADLES

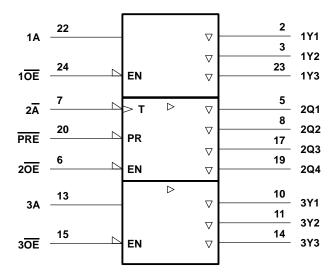
	INPUTS		OUTPUTS
2 <mark>0E</mark>	PRE	2 <mark>A</mark>	2Q1-2Q3
Н	Х	Х	Z
L	L	L	Н
L	Н	$\downarrow$	Toggle

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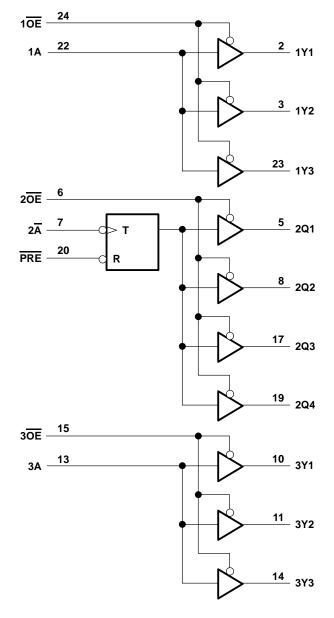
# CDC330 CLOCK DRIVER WITH 3-STATE OUTPUTS

SCAS329A - OCTOBER 1993 - REVISED MARCH 1994

# logic symbol<sup>†</sup>



<sup>†</sup> This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.



logic diagram (positive logic)

### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>‡</sup>

Supply voltage range, V <sub>CC</sub>	−0.5 V to 7 V
Input voltage range, V <sub>I</sub> (see Note 1)	
Voltage range applied to any output in the disabled or power-off state, VO	$\dots \dots \dots \dots \dots \dots -0.5$ V to 5.5 V
Current into any output in the low state, IO	
Input clamp current, I <sub>IK</sub> (V <sub>I</sub> < 0)	–18 mA
Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0)	
Storage temperature range	−65°C to 150°C

<sup>‡</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.



## recommended operating conditions (see Note 2)

		MIN	MAX	UNIT
VCC	Supply voltage	4.75	5.25	V
VIH	High-level input voltage	2		V
VIL	Low-level input voltage		0.8	V
VI	Input voltage	0	VCC	V
IOH	High-level output current		-32	mA
IOL	Low-level output current		32	mA
TA	Operating free-air temperature	0	70	°C

NOTE 2: Unused pins (input or I/O) must be held high or low.

#### electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP†	MAX	UNIT
VIK	V <sub>CC</sub> = 4.75 V,	lı = –18 mA				-1.2	V
VOH	V <sub>CC</sub> = 4.75 V,	I <sub>OH</sub> = – 32 mA		2			V
VOL	V <sub>CC</sub> = 4.75 V,	I <sub>OL</sub> = 32 mA				0.5	V
ЧΗ	V <sub>CC</sub> = 5.25 V,	V <sub>I</sub> = 2.7 V				50	μA
۱ <sub>IL</sub>	V <sub>CC</sub> = 5.25 V,	V <sub>I</sub> = 0.5 V				-50	μA
I <sub>OZ</sub>	V <sub>CC</sub> = 5.25 V,	$V_{O} = V_{CC} \text{ or } GND$				±50	μA
IO‡	$V_{CC} = 5.25 V,$	V <sub>O</sub> = 2.5 V		-30		-180	mA
			Outputs high		11	40	
ICC	$V_{CC} = 5.25 V,$ $V_{I} = V_{CC} \text{ or GND}$	I <sub>O</sub> = 0,	Outputs low		15	30	mA
			Outputs disabled		10	30	
Ci	V <sub>I</sub> = 2.5 V or 0.5 V				3		pF
Co	$V_{O} = 2.5 \text{ V or } 0.5 \text{ V}$				9		pF

<sup>†</sup> All typical values are at  $V_{CC} = 5 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ . <sup>‡</sup> Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

#### timing requirements over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

			MIN	MAX	UNIT
<sup>f</sup> clock	Clock froquonov	1A/3A (duty cycle 40 – 60%)		67	MHz
		$2\overline{A}$ (duty cycle 40 – 60%)		100	MHz
t <sub>w</sub>	Pulse duration	1A/3A low	5.9		
		1A/3A high	5.9		
		2A low	2.8		ns
		2A high	4.5		
		PRE low	3		
t <sub>su</sub>	Setup time	PRE inactive before $2\overline{A}\downarrow$	2		ns



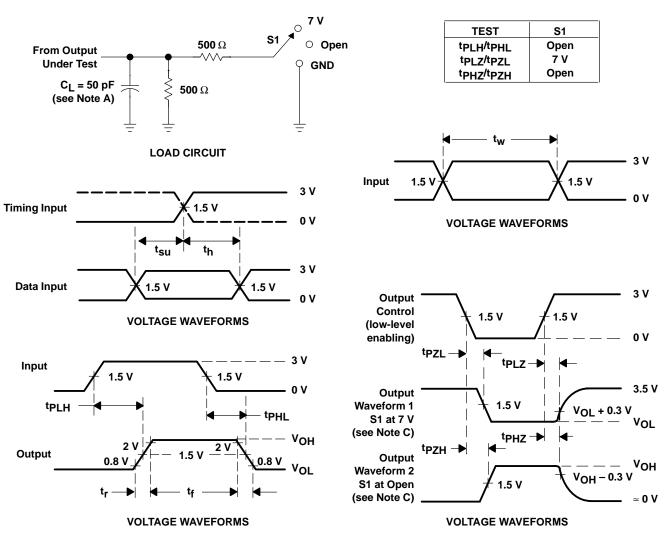
switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 3 and Figures 1 and 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	MIN MAX	UNIT	
, t	1A or 3A	Any 1Y or 3Y	67	MHz	
f <sub>max</sub> †	24	Any Q	100	MIL	
<sup>t</sup> PLH	• • • • <del>•</del>		11		
<sup>t</sup> PHL	Any A°or A <sup>^</sup>	Any Y or Q	10.5	ns	
<sup>t</sup> PHL	PRE	Any Q	12.5	ns	
<sup>t</sup> PZH	Any OE Any Y or Q	Any Y or Q	9	ns	
<sup>t</sup> PZL			8.5	115	
<sup>t</sup> PHZ	Any OE	Any Y or Q	8.5	ns	
<sup>t</sup> PLZ	ANY CE	Any For Q	9	115	
	1A	Any 1Y	0.4		
	3A	Any 3Y	0.4		
<sup>t</sup> sk(o)	1A or 3A	Any 1Y or 3Y	0.5	ns	
	2A	Any Q	0.4		
<sup>t</sup> sk(pr)	Any A or A	Any Y or Q	1	ns	

<sup>†</sup> Duty cycle 40 – 60%

NOTE 3: All specifications are valid only for all outputs switching.





### PARAMETER MEASUREMENT INFORMATION

#### NOTES: A. CL includes probe and jig capacitance.

- B. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>O</sub> = 50  $\Omega$ , t<sub>f</sub>  $\leq$  2.5 ns, t<sub>f</sub>  $\leq$  2.5 ns.
- C. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- D. The outputs are measured one at a time with one transition per measurement.

#### Figure 1. Load Circuit and Voltage Waveforms



## **CDC330 CLOCK DRIVER** WITH 3-STATE OUTPUTS SCAS329A - OCTOBER 1993 - REVISED MARCH 1994

nA nY1 ► tPHL8 tPLH1 TPHL1 nY2 tPLH2 tPHL2 <sup>t</sup>PLH9 ►<sup>t</sup>PHL9 nY3 ► tPLH3 ItPLH10 🕨 tPHL3 😽 tPHL10 2Ā 2Q1 <sup>t</sup>PLH4 ► <sup>t</sup>PHL4 2Q2 tPLH5 🕨 tPHL5 🗖 2Q3 LtPHL6 tPLH6 🔄 2Q4 ▶ t<sub>PLH7</sub> 😽 🔺 tPHL7 🗲

# PARAMETER MEASUREMENT INFORMATION

NOTES: A. Output skew,  $t_{Sk(0)}$ , is calculated as the greater of:

- The difference between the fastest and slowest of  $t_{PLHn}$  (n = 1, 2, 3) The difference between the fastest and slowest of  $t_{PLHn}$  (n = 4, 5, 6, 7)
- The difference between the fastest and slowest of  $t_{PLHn}$  (n = 8, 9, 10)
- The difference between the fastest and slowest of  $t_{PHLn}$  (n = 1, 2, 3)
- The difference between the fastest and slowest of  $t_{PHLn}$  (n = 4, 5, 6, 7)
- The difference between the fastest and slowest of  $t_{PHLn}$  (n = 8, 9, 10)
- B. Process skew, tsk(pr), is calculated the same as output skew, tsk(o), across multiple CDC330 devices under identical operating conditions.

# Figure 2. Waveforms for Calculation of t<sub>sk(o)</sub>, t<sub>sk(pr)</sub>



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